| Docket: PATENT |
|---|
| . COMBINED DECLARATION AND POWER OF ATTORNEY |
| (ORIGINAL, DESIGN, NATIONAL STAGE OF PCT, SUPPLEMENTAL, DIVISIONAL, CONTINUATION OR CIP) |
| As a below named inventor, I hereby declare that: |
| TYPE OF DECLARATION |
| This declaration is of the following type: (check one applicable item below) |
| x original design supplemental |
| Note: If the Declaration is for an International Application being filed as a divisional, continuation or continuation-in-part application, do <u>not</u> check next item; check appropriate one of last three items. |
| national stage of PCT |
| Note: If one of the following 3 items apply, then complete and also attach ADDED PAGES FOR DIVISIONAL, CONTINUATION OR CIP. |
| divisional |
| continuationcontinuation-in-part (CIP) |
| INVENTORSHIP IDENTIFICATION |
| WARNING: If the inventors are each not the inventors of all the claims, an explanation of the facts, including the ownership of all the claims at the time the last claimed invention was made, should be submitted. |
| My residence, post office address and citizenship are as stated below, next to my name. I believe that I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter that is claimed, and for which a patent is sought on the invention entitled: |
| TITLE OF INVENTION |
| METHOD FOR FORMING METAL-INSULATOR-METAL CAPACITOR OF SEMICONDUCTOR DEVICE |

SPECIFICATION IDENTIFICATION

| the specificat | tion of which: (complete (a), (b) or (c)) | |
|---------------------------|--|--|
| x (a | a) is attached hereto. | |
| ☐ (b | o) was filed on as Serial No as Serial No and was amended on (if applicable). | or |
| accord are th amend | dments filed after the original papers are deposited with the PTO that contain ded a filing date by being referred to in the Declaration. Accordingly, the a lose filed with the application papers or, in the case of a supplemental De dments claiming matter not encompassed in the original statement of invent TR 1.67. | mendments involved claration, are those |
| (c | c) was described and claimed in PCT International Application N filed on and as amended under PCT Article 19 (if any). | |
| ACKNO | WLEDGEMENT OF REVIEW OF PAPERS AND DUTY OF CANDOR | |
| - | ate that I have reviewed and understand the contents of the i, including the claims, as amended by any amendment referred to | |
| | ge the duty to disclose information, which is material to patents of Federal Regulations, § 1.56, | ability as defined |
| | (also check the following items, if desired) | |
| | and which is material to the examination of this applinformation where there is a substantial likelihood that a reaswould consider it important in deciding whether to allow the apas a patent, and | onable Examiner |
| | in compliance with this duty, there is attached an inform statement, in accordance with 37 CFR 1.98. | nation disclosure |
| • | PRIORITY CLAIM (35 U.S.C. 9 119(a)-(d)) | |
| | | |

I hereby claim foreign priority benefits under Title 35, United States Code, § 119(a)-(d) of any foreign application(s) for patent or inventor's certificate or of any PCT international application(s) designating at least one country other than the United States of America listed below and have also identified below any foreign application(s) for patent or inventor's certificate or any PCT international application(s) designating at least one country other than the United States of America filed by me on the same subject matter having a filing date before that of the application(s) of which priority is claimed.

| | (comple | ete (d) or (e)) | | |
|---|--|------------------------|--------------------------|---|
| (d) no such | applications have been | filed. | | |
| x (e) such ap | plications have been file | d as follow | VS. | |
| | is entered above and the invertee the detection of the detection (e), enter the detection of the detection o | | | |
| (6 M | EIGN/PCT APPLICATION(S ONTHS FOR DESIGN) PRIC Y PRIORITY CLAIMS UND | OR TO THIS | APPLICATION | |
| COUNTRY (OR NDICATE IF PCT | APPLICATION NUMBER | | OF FILING nonth/year) | PRIORITY CLAIMED UNDER 35 USC 119 |
| Republic of Korea | epublic of Korea 2003-3951 21/01/2003 | | | |
| | | | | ☐ YES NO ☐ |
| CLAIM FOR | BENEFIT OF PRIOR U.S. (35 U.S. | PROVISION C. º 119(| | ON(S) |
| hereby claim the borovisional applicati | enefit under Title 35, Unon(s) listed below: | nited State | s Code, § 119 | (e) of any United States |
| PROVISIONAL APPLICATION NUMBER | | | FIL | ING DATE |
| | | · · · · · · · | | |
| | | | | |
| | APPLICATION(S), IF ANY THS FOR DESIGN) PRIOR | | | |
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If the application filed more than 12 months from the filing date of this application is a PCT filing Note: forming the basis for this application entering the United States as (1) the national stage or (2) a continuation, divisional, or continuation-in-part, then also complete ADDED PAGES TO COMBINED DECLARATION AND POWER OF ATTORNEY FOR DIVISIONAL, CONTINUATION OR CIP APPLICATION for benefit of the prior U.S. or PCT application(s) under 35 U.S.C. § 120.

POWER OF ATTORNEY

I hereby appoint the following practitioner(s) to prosecute this application and transact all business in the Patent and Trademark Office connected therewith (list name and registration number).

Thomas F. Peterson, 24790; Richard J. Streit, 25765; Donald P. Reynolds, 26220; W. Dennis Drehkoff, 27193; Vangelis Economou, 32341; Brian W. Hameder, 45613; Valerie Neymeyer-Tynkov, Reg. 46956; Paul B. West, 18947; Joseph H. Handelman, 26179; Peter D. Galloway 27885; John Richards, 31503; Iain C. Baillie, 24090; Richard P. Berg, 28145

Attached, as part of this declaration and power of attorney, is the authorization of the above-named practitioner(s) to accept and follow instructions from my representative(s).

SEND CORRESPONDENCE TO:

DIRECT TELEPHONE CALLS TO:

(Name and telephone number)

Richard J. Streit c/o Ladas & Parry 224 South Michigan Avenue Suite 1200 Chicago, Illinois 60604

(312) 427-1300

DECLARATION

I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

SIGNATURE(S)

Note: Carefully indicate the family (or last) name, as it should appear on the filing receipt and all other documents.

Full name of sole or first inventor

| Yi Sun | <u></u> | CHUNG | | |
|----------------------|-------------------------------------|----------------------------|--|--|
| (Given Name) | (Middle Initial or Name) | (Family (or Last) Name) | | |
| Inventor's signature | Vsching | | | |
| Date December 1, 20 | Country of Citizenship | Republic of Korea | | |
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